



FIGURE 1

TOP VIEW 08635260

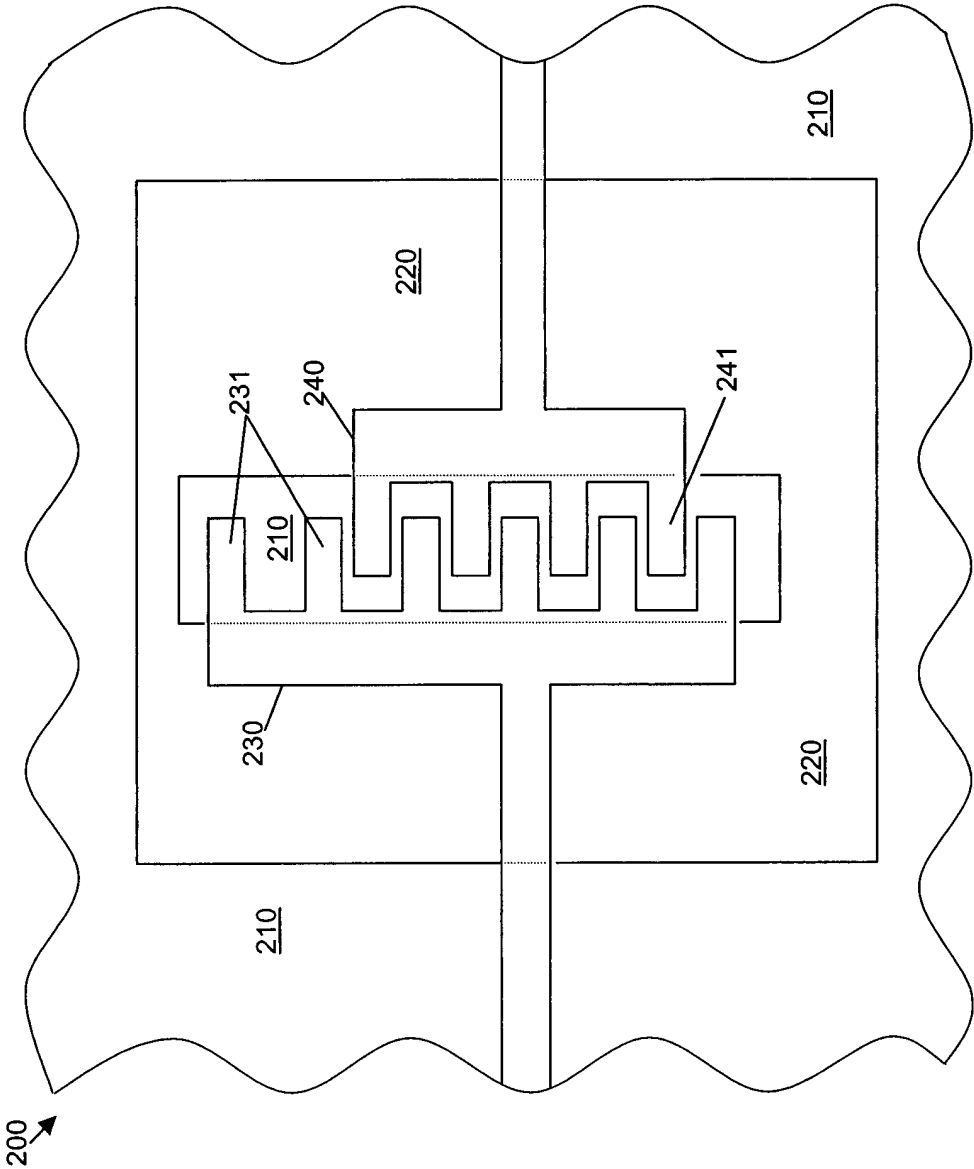


FIGURE 2

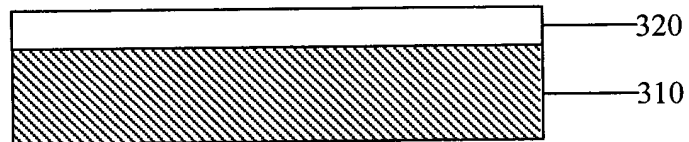
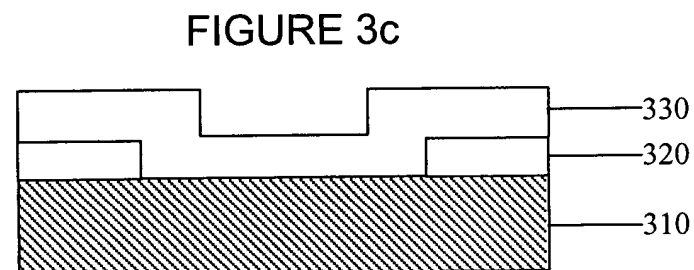
[illegible]

Figure 1 is a cross-sectional diagram of a substrate. The substrate consists of a top layer and a bottom layer. The top layer is divided into two regions, labeled 320 and 310. The bottom layer is labeled 310.



A cross-sectional view of a semiconductor device structure. It shows a substrate 310 with a hatched pattern. On top of the substrate is a layer 320. Above layer 320 are several rectangular blocks of varying heights and widths, collectively labeled as 330.

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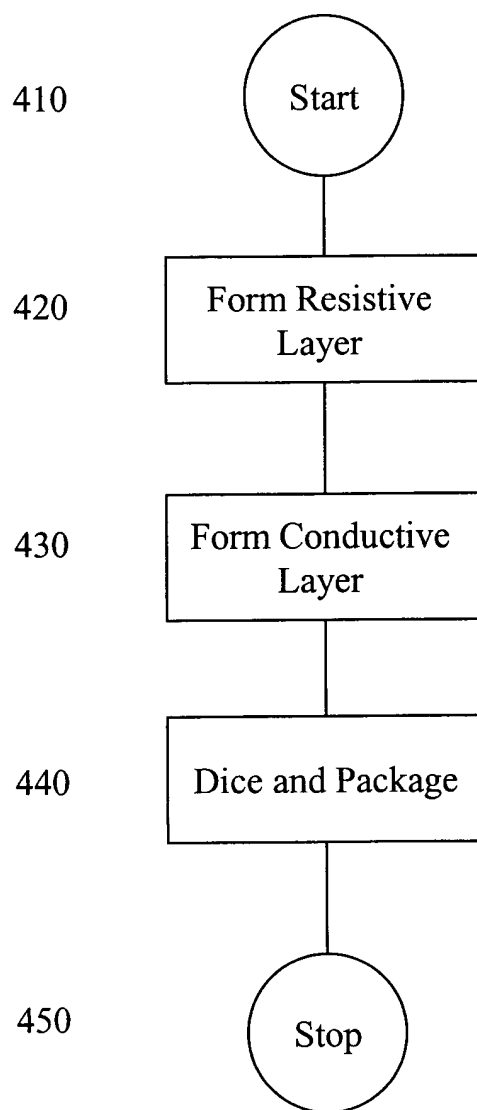


FIGURE 4